

Excellent Integrated System Limited

Stocking Distributor

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Vishay Semiconductor/Diodes Division VB20150S-M3/8W

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Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite

Datasheet of VB20150S-M3/8W - DIODE SCHOTTKY 20A 150V TO-263AB

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com





Vishay General Semiconductor

High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.55$ V at $I_F = 5.0$ A

TMBS®

TO-263AB

www.vishay.com



VB20150S

PRIMARY CHARACTERISTICS				
Package	TO-263AB			
I _{F(AV)}	20 A			
V _{RRM}	150 V			
I _{FSM}	160 A			
V_F at I_F = 20 A	0.75 V			
T _J max.	150 °C			
Diode variations	Single die			

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Material categorization
 HALOGEN
 for definitions of compliance please see
 FREE
 www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters, and reverse battery protection.

MECHANICAL DATA

Case: TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)				
PARAMETER	SYMBOL	VB20150S	UNIT	
Maximum repetitive peak reverse voltage	V _{RRM}	150	V	
Maximum average forward rectified current (fig. 1)	I _{F(AV)}	20	A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	160	A	
Voltage rate of change (rated V _R)	dV/dt	10 000	V/µs	
Operating junction and storage temperature range	T _J , T _{STG}	-55 to +150	°C	

ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode ⁽¹⁾	I _F = 5.0 A	T _A = 25 °C	V _F	0.69	-	V	
	I _F = 10 A			0.84	-		
	I _F = 20 A			1.15	1.43		
	I _F = 5.0 A	T _A = 125 °C		0.55	-		
	I _F = 10 A			0.64	-		
	I _F = 20 A			0.75	0.82		
Reverse current per diode ⁽²⁾	V _R = 100 V -	T _A = 25 °C	I _R	2	-	μA	
		T _A = 125 °C		2.5	-	mA	
	$V_{P} = 150 V$	T _A = 25 °C		-	250	μA	
		T _A = 125 °C		5	25	mA	

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

Revision: 30-Jun-14 Document Number: 87994 For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



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VB20150S-M3

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THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	VB20150S	UNIT		
Typical thermal resistance	$R_{\theta JC}$	2.0	°C/W		

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-263AB	VB20150S-M3/4W	1.39	4W	50/tube	Tube	
TO-263AB	VB20150S-M3/8W	1.39	8W	800/reel	Tape and reel	

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

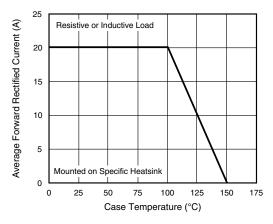


Fig. 1 - Maximum Forward Current Derating Curve

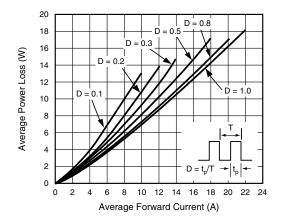


Fig. 2 - Forward Power Dissipation Characteristics Per Diode

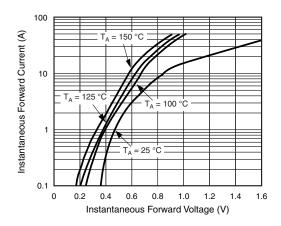


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

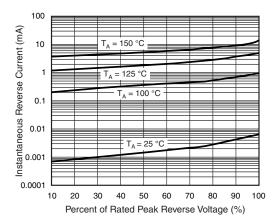


Fig. 4 - Typical Reverse Characteristics Per Diode



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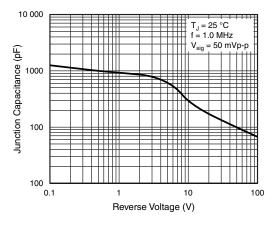


Fig. 5 - Typical Junction Capacitance Per Diode

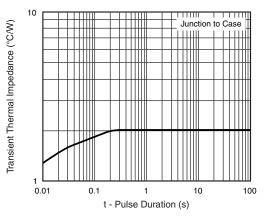
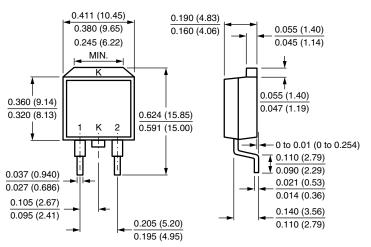


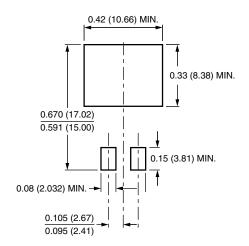
Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



TO-263AB

Mounting Pad Layout



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